NSN 5962-01-306-5557

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-306-5557

Overall Lengths
Overall Length:
1.490 inches
Overall Height: 0.432 inches

Overall Width:
0.620 inches
Body Length:
1.490 inches
Body Width:
0.610 inches
Body Height:
0.107 inches
Maximum Power Dissipation Rating:
1.155 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and burn in and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
19 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
30.00 milliamperes forward current, nonrepetitive, peak total value absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

28 printed circuit

NSN 5962-01-306-5557

Memory Microcircuit - Page 2 of 2



Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0